

Electrodynamics on Fermi Cyclides in Nodal Line Semimetals

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We study the frequency dependent conductivity of nodal-line semimetals (NLSMs) focusing on the effects of carrier density and energy dispersion on the nodal line. We find that the low frequency conductivity has a rich spectral structure which can be understood using scaling rules derived from the geometry of their Dupin-cyclide Fermi surfaces. We identify different frequency regimes, find scaling rules for the optical conductivity in each and demonstrate them with numerical calculations of the inter- and intraband contributions to the optical conductivity using a low energy model for a generic NLSM.

Introduction — Interest in topological states of quantum matter has led to the identification of new gapless electronic states that support nontrivial geometric structures in their band structures at or near the Fermi energy. In topological semimetals, the conduction and valence bands contact at points or lines in momentum space, and the band degeneracy at the contact is protected by symmetries such as crystalline and time reversal symmetries. Among the three dimensional topological semimetals, Weyl (Dirac) semimetals have non-degenerate (degenerate) conduction and valence bands which touch at discrete points, whereas in nodal line semimetals (NLSMs), the two bands cross on closed lines in momentum space [1–4].

When protected by a mirror symmetry, such a nodal line is “flat” in the sense that it lies in a single plane in $\mathbf{k}$ -space. However the contact line is not similarly constrained to occur on a constant energy surface. An energy dispersion on the nodal line has no effect on its topological character which is determined by the phase winding of the Bloch states around the singularity. However it generically forces the system into a semimetallic state with coexisting electron and hole pockets and an unconventional Fermi surface (FS) geometry, exhibiting the rich structures of Dupin cyclide geometries [5], as shown in Fig. 1. Here the geometry of the FS is determined by a combination of the energy dispersion of the contact line (tilt) and the Fermi energy which play a crucial role in determining various physical properties in NLSMs.

The optical conductivity of a low energy model for a NLSM in the absence of tilt has recently been studied [6]. However, once an energy tilt is introduced, there is a competition between two energy scales set by the amount of dispersion and by the chemical potential. In this work, we study the consequences of this competition for the low frequency conductivity of a NLSM and analyze its characteristic frequency dependence using the geometry of the Dupin cyclide. We find new spectral

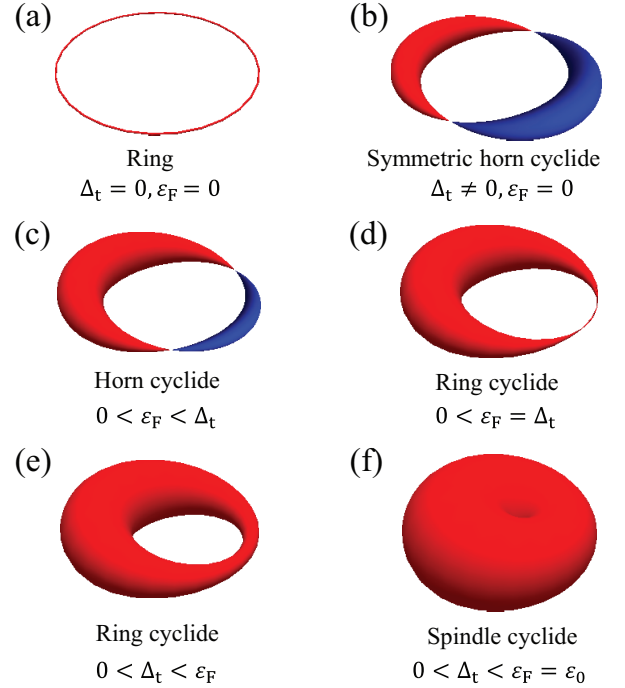


FIG. 1. Evolution of the Fermi surface (FS) as a function of tilt Δ_t and Fermi energy ϵ_F with red (blue) indicating the electron (hole) pocket. (a) At zero Fermi energy with zero tilt, the FS has a one dimensional ring shape sitting on the zero energy plane. (b) With a finite tilt, the ring shape evolves into symmetric horn cyclide containing both electron and hole pockets symmetrically, which vanish at two contact points. Upon increasing the Fermi energy, the electron and hole pockets (c) become asymmetric and the contact points move out from the symmetrical axis, (d) converging into a single point when the Fermi energy equals the tilt energy, and (e) vanish when the Fermi energy becomes larger than the tilt energy. (f) When the Fermi energy equals the energy scale of the ring radius, the FS is merged into a sphere-like shape with no holes in the center, similar to that of Weyl semimetals.

features that occur as a result of its unconventional geometry. For a non-zero Fermi energy smaller than the tilt energy scale, full Pauli blocking is prevented and instead all three diagonal components of the optical conductivity

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ity tensor show linear scaling with frequency. For the Fermi energy larger than the tilt energy, the interband optical conductivity recovers a gap due to Pauli blocking. We find nonanalytic features in both the frequency dependence of the interband conductivity and the chemical potential dependence of the Drude stiffness which arises from Lifshitz transitions of the FS.

Model — In the continuum approximation, the minimal Hamiltonian for tilted NLSMs that captures the essential features of its low energy excitations takes the form of 2 by 2 matrix given by [7, 8]:

$$H = \hbar v q_\rho \sigma_x + \hbar v k_z \sigma_y + \hbar \mathbf{v}_t \cdot \mathbf{k} \sigma_0, \quad (1)$$

where σ_x and σ_y are the Pauli matrices, σ_0 is the identity matrix, $\mathbf{v}_t$ is the tilt velocity, $q_\rho = k_\rho - k_0$, $k_\rho = \sqrt{k_x^2 + k_y^2}$, and k_0 is the radius of the nodal ring. The eigenenergies of the Hamiltonian are given by

$$\varepsilon_\pm(\mathbf{k}) = \pm \hbar v \sqrt{q_\rho^2 + k_z^2} + \hbar \mathbf{v}_t \cdot \mathbf{k}, \quad (2)$$

which has a ring shape zero-energy contour with a slope of $\mathbf{v}_t$. In the following, we consider tilt only in the in-plane direction because it produces electron-hole pockets, leading to qualitative changes in the optical conductivity, whereas tilt along the perpendicular axis has little effect on the optical conductivity unless it is so extreme that the system is in a type II semimetallic state [9]. Without loss of generality, we therefore set $\mathbf{v}_t = v_t \hat{x}$.

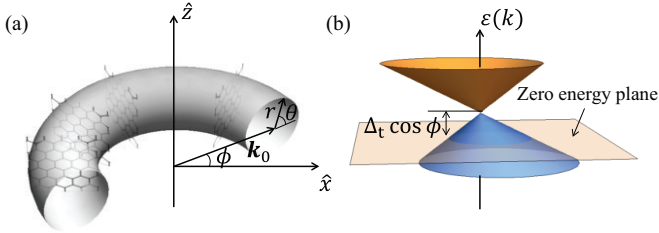


FIG. 2. (a) Schematic illustration of toroidal coordinates and graphene sheets standing perpendicular to the nodal-line plane. (b) The Dirac cone energy dispersion of the graphene sheet located at ϕ . Note that the Dirac cone is shifted from the zero energy by $\Delta_t \cos \phi$.

Remarkably, in toroidal coordinates [9], this NLSM Hamiltonian in Eq. (1) can be written in the same form as low energy graphene Hamiltonian, but expressed in polar coordinates (r, θ) centered at $\mathbf{k}_0$ [see Fig. 2(a)]:

$$H = \varepsilon_0 \begin{pmatrix} 0 & \tilde{r} e^{-i\theta} \\ \tilde{r} e^{i\theta} & 0 \end{pmatrix} + \Delta_t (1 + \tilde{r} \cos \theta) \cos \phi \sigma_0, \quad (3)$$

where $\tilde{r} = r/k_0$, $\varepsilon_0 = \hbar v k_0$, and $\Delta_t = \hbar v_t k_0$. Thus, in the energy range where the toroidal structure is maintained, we can consider NLSMs as a collection of graphene sheets with tilt in the x -direction and the Dirac point shifted from zero energy by $\Delta_t \cos \phi$ [see Fig. 2(b)].

Optical conductivity obtained from a collection of graphene sheets — In the linear response limit, we obtain the optical conductivity of NLSMs by summing up individual contributions from each of the graphene sheets:

$$\sigma_{ii}^{\text{NLSM}} = k_0 \int_0^{2\pi} \frac{d\phi}{2\pi} \sigma^{\text{gr}}(\phi) \mathcal{F}_{ii}(\phi), \quad (4)$$

where $i = x, y, z$, $\sigma^{\text{gr}}(\phi)$ is the optical conductivity of a graphene sheet located at ϕ with tilt in the x -direction, and $\mathcal{F}_{xx}(\phi) = \cos^2 \phi$, $\mathcal{F}_{yy}(\phi) = \sin^2 \phi$, $\mathcal{F}_{zz}(\phi) = 1$ are geometric factors from the projection of an external electric field on the graphene sheet and that of the in-plane velocity of graphene on the current direction. Note that Eq. (4) is valid for $\hbar\omega < 2\varepsilon_0$ where the toroidal structure is maintained.

First, consider the case of $\Delta_t = 0$. Since the optical conductivity from a single Dirac cone filled to energy ε_F is given by $\sigma^{\text{gr}}(\phi) = \frac{e^2}{16\hbar} \Theta(\hbar\omega - 2|\varepsilon_F|)$ [10], the optical conductivity of the NLSM is

$$\frac{\sigma_{ii}}{\sigma_0} \approx \begin{cases} \frac{1}{2} \Theta(\hbar\omega - 2|\varepsilon_F|) & \text{for } i = x, y, \\ \Theta(\hbar\omega - 2|\varepsilon_F|) & \text{for } i = z, \end{cases} \quad (5)$$

where $\sigma_0 = \frac{e^2 k_0}{16\hbar}$. Thus, for $\hbar\omega < 2|\varepsilon_F|$ the optical conductivity vanishes due to Pauli blocking, whereas for $2|\varepsilon_F| < \hbar\omega < 2\varepsilon_0$, it remains constant [6].

For $\Delta_t \neq 0$, the conductivity should be modified to take into account i) the shift of the Dirac point from zero energy [first term of σ_0 in Eq. (3)] and ii) the tilted linear band dispersion (second term). At low frequencies ($\hbar\omega \ll \varepsilon_0$), however, when the Dirac points lie close to zero energy, the tilt in the band dispersion is negligible. Thus, $\sigma_{ii}(\omega)$ at low frequencies can be obtained using $\sigma^{\text{gr}}(\phi) \approx \frac{e^2}{16\hbar} \Theta(\hbar\omega - 2|\varepsilon_F - \Delta_t \cos \phi|)$ in Eq. (4), giving

$$\frac{\sigma_{ii}}{\sigma_0} \approx \int_0^{2\pi} \frac{d\phi}{2\pi} \Theta(\hbar\omega - 2|\varepsilon_F - \Delta_t \cos \phi|) \mathcal{F}_{ii}(\phi). \quad (6)$$

In the following, we present numerically calculated optical conductivities over a wide frequency range in the presence of tilt and finite Fermi energy by evaluating the Kubo formula [see Eq. (6) in Supplemental Material (SM)]. We analyze the results by investigating the geometry of the PS for interband transitions and the low frequency analytic forms obtained from Eq. (6). Here, the PS for interband transitions is given by the intersection between the outside of the FS and the PS allowed by energy conservation. For a given frequency ω , the PS for NLSMs allowed by energy conservation is the surface of the momentum space torus which satisfies $\hbar\omega = \varepsilon_+(\mathbf{k}) - \varepsilon_-(\mathbf{k})$.

Optical conductivity with $\varepsilon_F = 0$ — We first consider the case where $\varepsilon_F = 0$ in the presence of tilt. Figures 3 (a) and (b) show calculated optical conductivities with tilt energies of $\Delta_t = 0.3\varepsilon_0$ and $\Delta_t = 0.6\varepsilon_0$, respectively. Note that the optical conductivities show kink structures at transitions between different frequency domains (I, II and

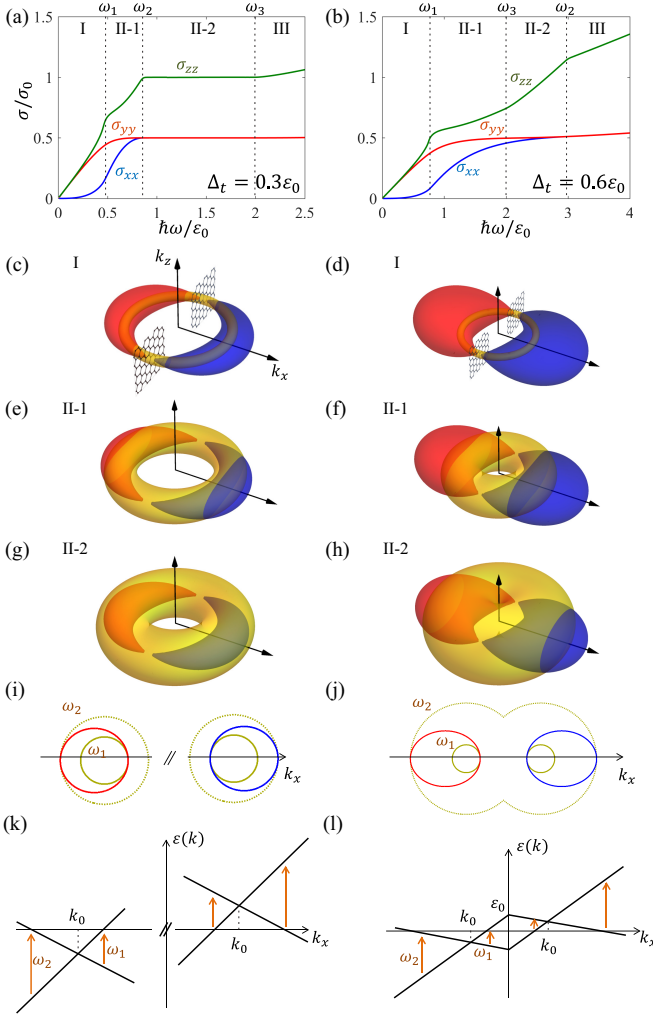


FIG. 3. (a), (b) Calculated optical conductivities of NLSMs for $\varepsilon_F = 0$ with two different tilt energies of (a) $\Delta_t = 0.3\varepsilon_0$ and (b) $\Delta_t = 0.6\varepsilon_0$. Regions I, II-1, II-2, III represent the frequency domains in which the PS for interband transitions grows continuously without any abrupt changes. (c)-(h) The PS allowed by energy conservation indicated by a yellow torus along with electron (red) and hole (blue) pockets in different frequency domains. Note that in region I the PS allowed for interband transitions consists of two local domains, while in region II they merge together to form a connected geometry. (i), (j) Cross-sectional views of the electron-hole pockets and the PS allowed by energy conservation in the $k_x - k_z$ plane at the frequencies of $\omega = \omega_1$ (yellow solid) and $\omega = \omega_2$ (yellow dashed), where the PS allowed for interband transitions changes its geometry leading to kink structures in the optical conductivity. (k), (l) Energy band dispersions along the k_x -axis with $k_y = k_z = 0$ for (k) $\Delta_t = 0.3\varepsilon_0$ and (l) $\Delta_t = 0.6\varepsilon_0$. The geometrical changes occur at frequencies corresponding to the onset of interband transitions indicated by arrows.

III) and characteristic frequency dependences determined by the tilt energies.

In region I, the optical conductivity in the tilt direction is $\sigma_{xx} \propto \omega^3$ at low frequencies while those in the other directions (σ_{yy} and σ_{zz}) are $\propto \omega$ [see region I of Figs. 3 (a)

and (b)]. Figures 3 (c) and (d) show the corresponding PS for interband transitions, which is divided into two separated islands located at $\phi = \pm \frac{\pi}{2}$. As demonstrated above in Eq. (6), we can express the optical conductivity by averaging contributions from the graphene sheets that occupy these two isolated regions. In the low frequency limit, in the vicinity of the contact points, the optical conductivity is approximately given by

$$\begin{aligned} \frac{\sigma_{ii}}{\sigma_0} &\approx \int_{\phi \sim \pm \frac{\pi}{2}} \frac{d\phi}{2\pi} \Theta(\hbar\omega - 2|\Delta_t \cos \phi|) \mathcal{F}_{ii}(\phi) \\ &\approx \frac{2}{\pi} \int_0^{\frac{\hbar\omega}{2\Delta_t}} d\phi \mathcal{F}_{ii}\left(\phi + \frac{\pi}{2}\right). \end{aligned} \quad (7)$$

With the expansion of $\mathcal{F}_{ii}(\phi + \frac{\pi}{2})$ around $\phi = 0$, the resulting conductivities in the lowest order are

$$\frac{\sigma_{ii}}{\sigma_0} = \begin{cases} \frac{1}{12\pi} \left(\frac{\hbar\omega}{\Delta_t}\right)^3 & \text{for } i = x, \\ \frac{\hbar\omega}{\pi\Delta_t} & \text{for } i = y, z, \end{cases} \quad (8)$$

which agree with our numerical results.

At the intersection between I and II-1 regions, the PS allowed by energy conservation (yellow torus) begins to touch the boundary of electron (red) and hole (blue) pockets, and the two isolated PS regions for interband transitions merge forming a connected geometry distinguished from that in region I [see Figs. 3(e) and (f)]. Note that this change of geometry produces a kink in σ_{ii} seen most clearly in σ_{zz} because of its ϕ -independent projection factor [$\mathcal{F}_{zz}(\phi) = 1$; see Eq. (4)]. Such a geometrical change also occurs at the intersection between II-1 and II-2 regions giving a kink in σ_{zz} . By observing the cross sectional view of the PS allowed by energy conservation and the FS in the $k_x - k_z$ plane [see Figs. 3 (i) and (j)], we can calculate the frequencies at which kinks appear. Alternatively, since the geometrical changes associated with additional interband transitions occur along the k_x -axis, the problem of finding kink frequencies is reduced to obtaining ω_1 and ω_2 in Figs. 3 (k) and (l): $\hbar\omega_1 = \frac{2\Delta_t}{\varepsilon_0 + \Delta_t}\varepsilon_0$, $\hbar\omega_2 = \frac{2\Delta_t}{\varepsilon_0 - \Delta_t}\varepsilon_0$.

In region II-2, for $\Delta_t = 0.3\varepsilon_0$, the PS allowed by energy conservation [yellow torus in Fig. 3.(g)] covers the whole FS while keeping its toroidal structure similar to the untilted case, thus the optical conductivity shows flat behavior with *exactly the same height as that of untilted NLSMs*. For $\Delta_t = 0.6\varepsilon_0$, however, the PS allowed by energy conservation [yellow sphere-like manifold in Fig. 3.(h)] is no longer a torus and does not fully cover the whole FS, exhibiting a monotonic increase in σ_{zz} instead of the flat behavior. Note that the PS allowed by energy conservation changes its geometry from a torus to a sphere-like manifold at the frequency $\hbar\omega_3 = 2\varepsilon_0$. Thus, the condition for the existence (absence) of the flat region can be obtained from the condition $\omega_2 < \omega_3$ ($\omega_2 > \omega_3$), leading to $\Delta_t < 0.5\varepsilon_0$ ($\Delta_t > 0.5\varepsilon_0$).

In region III, the PS allowed by energy conservation for both $\Delta_t = 0.3\varepsilon_0$ and $\Delta_t = 0.6\varepsilon_0$ merge into a sphere-like

geometry covering the whole FS, similar to that of Weyl semimetals. Thus, at high frequencies in this frequency domain, the optical conductivity shows a linear behavior, as already shown in previous studies [6].

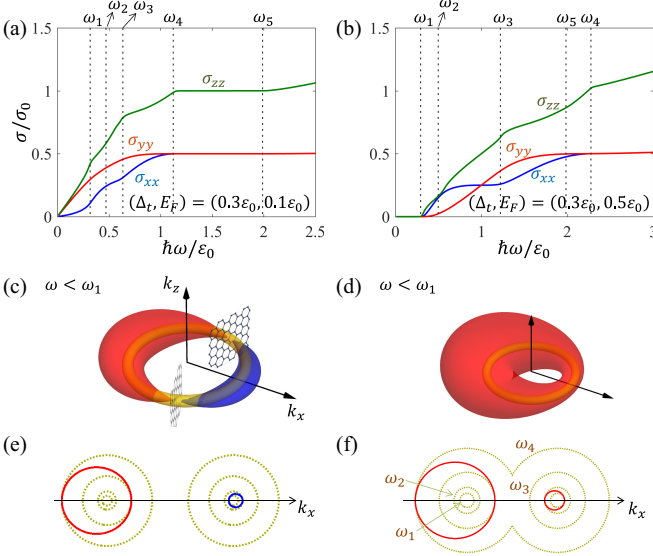


FIG. 4. (a), (b) Calculated optical conductivities of tilted NLSMs with $\Delta_t = 0.3\varepsilon_0$ for two different Fermi energies of (a) $\varepsilon_F = 0.1\varepsilon_0$ and (b) $\varepsilon_F = 0.5\varepsilon_0$. (c), (d) The PS allowed by energy conservation indicated by a yellow torus along with electron (red) and hole (blue) pockets in the low frequency domain for (c) $\varepsilon_F = 0.1\varepsilon_0$ and (d) $\varepsilon_F = 0.5\varepsilon_0$. (e), (f) Cross-sectional views of the electron-hole pockets and the PS allowed by energy conservation in the k_x - k_z plane at frequencies where kinks appear in the optical conductivity.

Optical conductivity with $\varepsilon_F \neq 0$ — Next, we consider the case where $\varepsilon_F \neq 0$ in the presence of tilt. Figure 4 (a) and (b) show calculated optical conductivities of NLSMs for $\varepsilon_F = 0.1\varepsilon_0$ and $\varepsilon_F = 0.5\varepsilon_0$, respectively, with $\Delta_t = 0.3\varepsilon_0$. At low frequencies, the optical conductivity for $\varepsilon_F = 0.1\varepsilon_0$ increases linearly with increasing ω , whereas that for $\varepsilon_F = 0.5\varepsilon_0$ exhibits an optical gap.

To address the difference in the low frequency behaviors, in Figs. 4 (c) and (d) we show the PS allowed by energy conservation corresponding to a low frequency range along with electron-hole pockets. For $\varepsilon_F = 0.1\varepsilon_0$, there is available PS for interband transitions consisting of two separate local domains located around the contact points between the electron and hole pockets. Similarly as we did for $\varepsilon_F = 0$, after replacing $|\Delta_t \cos \phi|$ with $|\varepsilon_F - \Delta_t \cos \phi|$ in Eq. (7), we obtain the low frequency optical conductivity as $\frac{\sigma_{ii}}{\sigma_0} \approx C_i \frac{\hbar\omega}{\pi\Delta_t}$ where $i = x, y, z$, $\phi_0 = \cos^{-1}\left(\frac{\varepsilon_F}{\Delta_t}\right)$ is the location of graphene sheets sitting around the PS for interband transitions, $C_x = \frac{(\frac{\varepsilon_F}{\Delta_t})^2}{\sqrt{1-(\frac{\varepsilon_F}{\Delta_t})^2}}$, $C_y = \sqrt{1-(\frac{\varepsilon_F}{\Delta_t})^2}$, and $C_z = \frac{1}{\sqrt{1-(\frac{\varepsilon_F}{\Delta_t})^2}}$. Note that in the presence of finite ε_F , the linear term dominates over the cubic one in the op-

tical conductivity along the tilt direction, in contrast to the $\varepsilon_F = 0$ case [see Eq. (7)]. (For $\varepsilon_F = \Delta_t$ case, see Sec. III in SM.)

For $\varepsilon_F = 0.5\varepsilon_0$, there is no available PS for interband transitions at low frequencies because the electron pocket becomes large enough to cover the entire PS allowed by energy conservation, leading to an optical gap due to Pauli blocking [see Fig. 4(d)]. The optical gap persists up to the frequency where the PS allowed by energy conservation touches the boundary of the electron pocket. Similarly as in the $\varepsilon_F = 0$ case, we can obtain the size of the optical gap to be $\hbar\omega_{\text{gap}} = 2\frac{\varepsilon_F - \Delta_t}{\varepsilon_0 + \Delta_t}\varepsilon_0$, and thus the condition for the existence of an optical gap: $\varepsilon_F > \Delta_t$.

As ε_F increases, the electron (hole) pocket grows (shrinks), because the number of electrons in the system increases. The imbalanced sizes of the electron and hole pockets lead to two more kinks compared with the $\varepsilon_F = 0$ case, as shown in Fig. 4(e) and (f). Similarly as in the $\varepsilon_F = 0$ case, we can obtain $\hbar\omega_1 = 2\left|\frac{\varepsilon_F - \Delta_t}{\varepsilon_0 + \Delta_t}\right|\varepsilon_0$, $\hbar\omega_2 = 2\left|\frac{\varepsilon_F - \Delta_t}{\varepsilon_0 - \Delta_t}\right|\varepsilon_0$, $\hbar\omega_3 = 2\left|\frac{\varepsilon_F + \Delta_t}{\varepsilon_0 + \Delta_t}\right|\varepsilon_0$, and $\hbar\omega_4 = 2\left|\frac{\varepsilon_F + \Delta_t}{\varepsilon_0 - \Delta_t}\right|\varepsilon_0$. It follows that the condition for the existence of flat region can be obtained from $\hbar\omega_4 > \hbar\omega_5 \equiv 2\varepsilon_0$, leading to $\Delta_t < \frac{1}{2}(\varepsilon_0 - \varepsilon_F)$ [9]. Here ω_5 is the frequency where the PS allowed by energy conservation changes its geometry from a torus to a sphere-like manifold.

The intraband contribution to optical conductivity gives rise to Drude peak at low frequencies whose weight also inherits a nonanalytic density dependence from the geometry of the FS. Interestingly these are seen most clearly in the *derivatives* of the weight with respect to Fermi energy, as shown in Fig. 5.

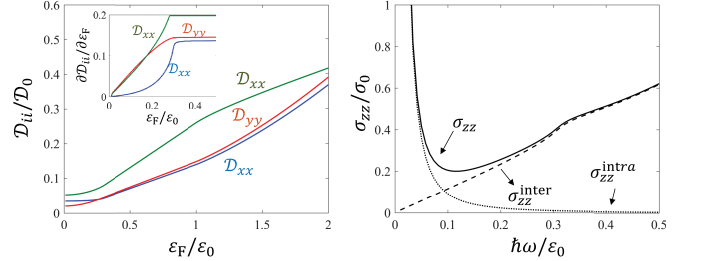


FIG. 5. (a) The Drude weight of tilted NLSMs with $\Delta_t = 0.3\varepsilon_0$ and (b) the intraband ($\sigma_{zz}^{\text{intra}}$, dotted line) and interband ($\sigma_{zz}^{\text{inter}}$, dashed line) contributions to the optical conductivity σ_{zz} (solid line). The inset to (a) shows the derivative of the Drude weight near $\varepsilon_F = \Delta_t$, where the Drude weight exhibits a nonanalytic kink behavior due to an abrupt change in the geometry of the FS. Here $\mathcal{D}_0 = \frac{e^2}{h}k_0\varepsilon_0$ and the Drude weight is defined to be $\sigma_{ii}^{\text{intra}} = \mathcal{D}_{ii}\delta(\hbar\omega)$. For (b), we use a finite broadening term $\eta = 0.001\varepsilon_0$ replacing the 0^+ term in Eq. (6) in SM.

Discussion — Introducing spin-orbit coupling (SOC) can gap out a nodal line and produce pairs of Weyl points [8]. In such cases, at frequencies below the SOC scale, the PS for interband transitions are spheres enclosing the Weyl nodes and the conductivity will revert to linear

frequency scaling known for Weyl semimetals (WSMs). Above the SOC energy, however, the separated PS recovers a toroidal shape and this will have the characteristic dependence found in our work. Recent calculations for WSMs in the TaAs class indicate that these materials are weakly broken line node systems where the tilt scale dominates the SOC scale [11]. Thus our analysis is applicable over a wide frequency range, and can be used as a signature of these new states of matter in optical experiments.

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Supplemental Material: Electrodynamics on Fermi Cyclides in Nodal Line Semimetals

I. TOROIDAL COORDINATE TRANSFORMATION

In this section, we present a toroidal coordinate transformation for nodal line semimetals (NLSMs) and obtain the density of states (DOS) in the absence of tilt. Let us consider the following coordinate transformation

$$\begin{aligned} k_x &\rightarrow (k_0 + r \cos \theta) \cos \phi, \\ k_y &\rightarrow (k_0 + r \cos \theta) \sin \phi, \\ k_z &\rightarrow r \sin \theta, \end{aligned} \quad (1)$$

which transforms Eq. (1) in the main text to Eq. (3) in the main text. Here, the Jacobian is given by $\mathcal{J}(r, \theta) = r(k_0 + r \cos \theta)$.

Using the toroidal coordinate transformation, consider the DOS in the absence of tilt ($\Delta_t = 0$). Then the eigenenergies are given by $\varepsilon_{\pm}(r) = \pm \hbar v r$ and the DOS can be easily obtained by

$$D(\varepsilon) = \frac{1}{(2\pi)^3} \int_0^{k_0} dr \int_0^{2\pi} d\theta \int_0^{2\pi} d\phi \mathcal{J}(r, \theta) \delta(\hbar v r - |\varepsilon|) \quad (2)$$

$$= \frac{1}{(2\pi)^2} \int_0^{k_0} dr \int_0^{2\pi} d\theta r(k_0 + r \cos \theta) \frac{1}{\hbar v} \delta\left(r - \frac{|\varepsilon|}{\hbar v}\right) \quad (3)$$

$$= \frac{k_0 |\varepsilon|}{2\pi \hbar^2 v^2}, \quad (4)$$

which is valid only for $|\varepsilon| < \varepsilon_0 \equiv \hbar v k_0$ where the toroidal structure is maintained. Including the higher energy regime, the DOS is given by

$$\frac{D(\varepsilon)}{D_0} = \begin{cases} \frac{|\varepsilon|}{\varepsilon_0} & (|\varepsilon| \leq \varepsilon_0), \\ \frac{|\varepsilon|}{\varepsilon_0} \left[\frac{1}{2} + \frac{1}{\pi} \sin^{-1} \left(\frac{\varepsilon_0}{|\varepsilon|} \right) + \frac{1}{\pi} \sqrt{\left(\frac{\varepsilon}{\varepsilon_0} \right)^2 - 1} \right] & (|\varepsilon| > \varepsilon_0), \end{cases} \quad (5)$$

where $D_0 = \frac{k_0 \varepsilon_0}{2\pi \hbar^2 v^2}$. Note that for $k_0 \rightarrow 0$ or $\varepsilon \rightarrow \infty$, the DOS approaches that for Weyl semimetals given by $D(\varepsilon) = \frac{\varepsilon^2}{2\pi^2 \hbar^3 v^3}$.

II. KUBO FORMULA FOR OPTICAL CONDUCTIVITY

In this section, we present the Kubo formula for the optical conductivity and derive the low frequency asymptotic expressions directly from the Kubo formula. Here we show that to leading order in ω , the optical conductivity obtained using the Kubo formula and that obtained by averaging optical conductivity of graphene sheets presented in the main text give the same result.

Optical conductivity. In the linear response and non-interacting limit, the optical conductivity can be calculated by using the Kubo Formula [1]:

$$\sigma_{ij}(\omega) = -\frac{ie^2}{\hbar} \sum_{s,s'} \int \frac{d^3 k}{(2\pi)^3} \frac{f_{s,\mathbf{k}} - f_{s',\mathbf{k}}}{\varepsilon_{s,\mathbf{k}} - \varepsilon_{s',\mathbf{k}}} \frac{M_i^{ss'}(\mathbf{k}) M_j^{s's}(\mathbf{k})}{\hbar\omega + \varepsilon_{s,\mathbf{k}} - \varepsilon_{s',\mathbf{k}} + i0^+}, \quad (6)$$

where $i, j = x, y, z$, $\varepsilon_{s,\mathbf{k}}$ and $f_{s,\mathbf{k}} = 1/[1 + e^{(\varepsilon_{s,\mathbf{k}} - \mu)/k_B T}]$ are the eigenenergy and the Fermi distribution function for the band index $s = \pm$ and wave vector $\mathbf{k}$, respectively, μ is the chemical potential and $M_i^{ss'}(\mathbf{k}) = \langle s, \mathbf{k} | \hbar \hat{v}_i | s', \mathbf{k} \rangle$ with the velocity operator $\hat{v}_i = \frac{1}{\hbar} \frac{\partial \hat{H}}{\partial k_i}$. We can separate the real part of the longitudinal optical conductivity to the intraband and interband contributions:

$$\sigma_{ii}^{\text{intra}}(\omega) = -\frac{\pi e^2}{\hbar} \sum_{s=\pm} \int \frac{d^3 k}{(2\pi)^3} \frac{\partial f_{s,\mathbf{k}}}{\partial \varepsilon_{s,\mathbf{k}}} |M_i^{ss}(\mathbf{k})|^2 \delta(\hbar\omega), \quad (7)$$

$$\sigma_{ii}^{\text{inter}}(\omega) = -\frac{\pi e^2}{\hbar} \int \frac{d^3 k}{(2\pi)^3} \frac{f_{-, \mathbf{k}} - f_{+, \mathbf{k}}}{\varepsilon_{-, \mathbf{k}} - \varepsilon_{+, \mathbf{k}}} |M_i^{-+}(\mathbf{k})|^2 \delta(\hbar\omega + \varepsilon_{-, \mathbf{k}} - \varepsilon_{+, \mathbf{k}}). \quad (8)$$

In the following we obtain the optical conductivity of NLSMs in the absence of tilt at zero Fermi energy. We show that for $\hbar\omega < 2\varepsilon_0$ the results are in agreement with those obtained by averaging graphene optical conductivities presented in the main text, whereas for $\hbar\omega > 2\varepsilon_0$ the optical conductivity of NLSMs shows linear frequency dependence as Weyl semimetal at high frequencies. In cylindrical coordinates ($k_x \rightarrow \rho \cos \phi$, $k_y \rightarrow \rho \sin \phi$), the eigenenergies of NLSMs are given by $\varepsilon_{\pm}(\rho, \phi, k_z) = \pm \hbar v \sqrt{k_z^2 + (\rho - k_0)^2}$ and the interband matrix elements are calculated to be

$$M_x^{-+}(\theta, \phi) = -i\hbar v \frac{k_z \cos \phi}{\sqrt{k_z^2 + (\rho - k_0)^2}}, \quad (9)$$

$$M_z^{-+}(\theta, \phi) = -i\hbar v \frac{\rho - k_0}{\sqrt{k_z^2 + (\rho - k_0)^2}}. \quad (10)$$

By inserting these into Eq. (8), we obtain

$$\begin{aligned} \sigma_{xx}^{\text{inter}}(\omega) &= \frac{e^2}{16\pi^2 \hbar} \int_0^\infty d\rho \rho \int_0^{2\pi} d\phi \int_{-\infty}^\infty dk_z \frac{\hbar v k_z^2 \cos^2 \phi}{[k_z^2 + (\rho - k_0)^2]^{\frac{3}{2}}} \delta(\hbar\omega - 2\hbar v \sqrt{k_z^2 + (\rho - k_0)^2}) \\ &= \frac{1}{2} \sigma_0 \left\{ \Theta(2 - \tilde{\omega}) + \Theta(\tilde{\omega} - 2) \left[\frac{1}{2} + \frac{1}{3\pi} \sqrt{\tilde{\omega}^2 - 4} \left(1 + \frac{2}{\tilde{\omega}^2} \right) + \frac{1}{\pi} \tan^{-1} \left(\frac{2}{\sqrt{\tilde{\omega}^2 - 4}} \right) \right] \right\}, \end{aligned} \quad (11)$$

and

$$\begin{aligned} \sigma_{zz}^{\text{inter}}(\omega) &= \frac{e^2}{16\pi^2 \hbar} \int_0^\infty d\rho \rho \int_0^{2\pi} d\phi \int_{-\infty}^\infty dk_z \frac{\hbar v (\rho - 1)^2}{[k_z^2 + (\rho - k_0)^2]^{\frac{3}{2}}} \delta(\hbar\omega - 2\hbar v \sqrt{k_z^2 + (\rho - k_0)^2}) \\ &= \sigma_0 \left\{ \Theta(2 - \tilde{\omega}) + \Theta(\tilde{\omega} - 2) \left[\frac{1}{2} + \frac{2}{3\pi} \sqrt{\tilde{\omega}^2 - 4} \left(1 - \frac{1}{\tilde{\omega}^2} \right) + \frac{1}{\pi} \tan^{-1} \left(\frac{2}{\sqrt{\tilde{\omega}^2 - 4}} \right) \right] \right\}, \end{aligned} \quad (12)$$

where $\sigma_0 = \frac{e^2 k_0}{16\hbar}$ and $\tilde{\omega} = \hbar\omega/\varepsilon_0$. Note that the optical conductivity is constant for $\hbar\omega < 2\varepsilon_0$, and begins to increase at $\hbar\omega = 2\varepsilon_0$. In the high frequency limit, $\sigma_{xx}^{\text{inter}}(\omega) \approx \frac{e^2}{96\hbar v} \omega$ and $\sigma_{zz}^{\text{inter}}(\omega) \approx \frac{e^2}{24\hbar v} \omega$, showing linear behaviors, as Weyl semimetals.

III. LOW FREQUENCY ASYMPTOTIC FORMS IN THE PRESENCE OF TILT AND FERMI ENERGY

Here we show derivations of the low frequency analytical expressions of the optical conductivity in the presence of tilt and Fermi energy. For the numerical calculation presented in the main text, we employed cylindrical coordinates that allow us to obtain valid expressions for the optical conductivity at all frequency range. For obtaining low frequency asymptotic expressions, however, it is not convenient to use cylindrical coordinates because the band structure appearing in the low-energy regime has a torus-like shape. Thus, we use the toroidal coordinates introduced in Sec. I for the derivation of low frequency asymptotic forms.

The eigenenergies and eigenstates of the Hamiltonian of NLSMs in toroidal coordinates [Eq. (3) in the main text] are given by $\varepsilon_{\pm}(r, \theta, \phi) = \pm \varepsilon_0 \tilde{r} + \Delta_t (1 + \tilde{r} \cos \theta) \cos \phi$ where $\tilde{r} = r/k_0$ and $|\pm, \mathbf{k}\rangle = \frac{1}{\sqrt{2}}(\pm 1, e^{i\phi})^T$, respectively. The velocity matrices are expressed as $\hat{v}_x = \cos \phi \sigma_x$, $\hat{v}_y = \sin \phi \sigma_x$, and $\hat{v}_z = \sigma_y$. It follows that the interband matrix elements used in the optical conductivity are

$$M_x^{-+}(\theta, \phi) = -i\hbar v \sin \theta \cos \phi, \quad (13)$$

$$M_y^{-+}(\theta, \phi) = -i\hbar v \sin \theta \sin \phi, \quad (14)$$

$$M_z^{-+}(\theta, \phi) = i\hbar v \cos \theta. \quad (15)$$

By inserting these into Eq. (8), we can obtain the interband part of the optical conductivity at zero temperature:

$$\begin{aligned} \sigma_{ii}^{\text{inter}}(\omega) &= \frac{\pi e^2}{\hbar} \int_0^{k_0} dr \int_0^{2\pi} d\theta \int_0^{2\pi} d\phi \frac{\mathcal{J}(r, \theta)}{(2\pi)^3} \frac{\mathcal{A}(\tilde{r}, \theta, \phi)}{2\varepsilon_0 \tilde{r}} |M_i^{-+}(\theta, \phi)|^2 \delta(\hbar\omega - 2\varepsilon_0 \tilde{r}) \\ &= \frac{e^2 k_0}{32\pi^2 \hbar} \int_0^{2\pi} d\theta \int_0^{2\pi} d\phi \left(1 + \frac{\hbar\omega}{2\varepsilon_0} \cos \theta \right) \mathcal{A} \left(\frac{\hbar\omega}{2\varepsilon_0}, \theta, \phi \right) \left| \tilde{M}_i^{-+}(\theta, \phi) \right|^2 \\ &= \sigma_0 I_i(\omega), \end{aligned} \quad (16)$$

where $\widetilde{M}_i^{-+}(\theta, \phi) = M_i^{-+}(\theta, \phi)/(\hbar v)$ and $\mathcal{A}(\tilde{r}, \theta, \phi) = \Theta[\varepsilon_F - \varepsilon_-(r, \theta, \phi)] - \Theta[\varepsilon_F - \varepsilon_+(r, \theta, \phi)]$ is the difference between the Fermi distribution functions (i.e., $f_{-, \mathbf{k}} - f_{+, \mathbf{k}}$) at zero temperature, which determines the integral area. Here $\hbar\omega < 2\varepsilon_0$ is assumed, and

$$\begin{aligned} I_i(\omega) &= \frac{1}{2\pi^2} \int_0^{2\pi} d\theta \left(1 + \frac{\hbar\omega}{2\varepsilon_0} \cos\theta\right) \int_0^{2\pi} d\phi \mathcal{A}\left(\frac{\hbar\omega}{2\varepsilon_0}, \theta, \phi\right) \left|\widetilde{M}_i^{-+}(\theta, \phi)\right|^2 \\ &= \frac{1}{2\pi^2} \int_0^{2\pi} d\theta \left(1 + \frac{\hbar\omega}{2\varepsilon_0} \cos\theta\right) \left[\int_{\phi_-(\theta, \omega)}^{\phi_+(\theta, \omega)} d\phi \left|\widetilde{M}_i^{-+}(\theta, \phi)\right|^2 + \int_{-\phi_+(\theta, \omega)}^{-\phi_-(\theta, \omega)} d\phi \left|\widetilde{M}_i^{-+}(\theta, \phi)\right|^2 \right] \\ &= \frac{1}{\pi^2} \int_0^{2\pi} d\theta \left(1 + \frac{\hbar\omega}{2\varepsilon_0} \cos\theta\right) \int_{\phi_-(\theta, \omega)}^{\phi_+(\theta, \omega)} d\phi \left|\widetilde{M}_i^{-+}(\theta, \phi)\right|^2, \end{aligned} \quad (17)$$

where $\phi_{\pm}(\omega) = \cos^{-1} \left[\frac{\varepsilon_F \mp \frac{\hbar\omega}{2}}{\Delta_t (1 + \frac{\hbar\omega}{2\varepsilon_0} \cos\theta)} \right]$. In the last line, we used $\left|\widetilde{M}_i^{-+}(\theta, \phi)\right|^2 = \left|\widetilde{M}_i^{-+}(\theta, -\phi)\right|^2$.

Assuming $\varepsilon_F < \Delta_t$, we can expand $\phi_{\pm}(\theta, \omega)$ around $\omega = 0$ as $\phi_{\pm}(\theta, \omega) \approx \phi_0 + \Delta_{\pm}(\theta, \omega)$ where $\phi_0 = \cos^{-1} \left(\frac{\varepsilon_F}{\Delta_t} \right)$ and

$$\Delta_{\pm}(\theta, \omega) = \pm \frac{\varepsilon_0 \pm \varepsilon_F \cos\theta}{2\sqrt{\Delta_t^2 - \varepsilon_F^2}} \frac{\hbar\omega}{2\varepsilon_0}. \quad (18)$$

Thus, at low frequencies $I_i(\omega)$ is calculated to be

$$I_i(\omega) \approx \frac{1}{\pi^2} \int_0^{2\pi} d\theta \left(1 + \frac{\hbar\omega}{2\varepsilon_0} \cos\theta\right) \int_{\Delta_-(\theta, \omega)}^{\Delta_+(\theta, \omega)} d\phi \left|\widetilde{M}_i^{-+}(\theta, \phi + \phi_0)\right|^2. \quad (19)$$

Note that the integral range of ϕ is $\Delta_-(\theta, \omega) < \phi < \Delta_+(\theta, \omega)$ and $\Delta_{\pm}(\theta, \omega) \propto \hbar\omega$ is small at low frequencies, thus the integrand can be expanded around $\phi = 0$. For $I_x(\omega)$, $\left|\widetilde{M}_x^{-+}(\theta, \phi)\right|^2 = \sin^2\theta \cos^2\phi$ thus we can obtain

$$\begin{aligned} I_x(\omega) &= \frac{1}{\pi^2} \int_0^{2\pi} d\theta \left(1 + \frac{\hbar\omega}{2\varepsilon_0} \cos\theta\right) \int_{\Delta_-(\theta, \omega)}^{\Delta_+(\theta, \omega)} d\phi \sin^2\theta \cos^2(\phi + \phi_0) \\ &\approx \frac{1}{\pi^2} \int_0^{2\pi} d\theta \left(1 + \frac{\hbar\omega}{2\varepsilon_0} \cos\theta\right) \sin^2\theta \int_{\Delta_-(\theta, \omega)}^{\Delta_+(\theta, \omega)} d\phi [\cos^2\phi_0 - \sin(2\phi_0)\phi - \cos(2\phi_0)\phi^2] \\ &\approx \frac{\left(\frac{\varepsilon_F}{\Delta_t}\right)^2}{\sqrt{1 - \left(\frac{\varepsilon_F}{\Delta_t}\right)^2}} \frac{\hbar\omega}{\pi\Delta_t}. \end{aligned} \quad (20)$$

Similarly, at low frequencies we can obtain the remaining components of the optical conductivity in units of σ_0 as

$$I_y(\omega) \approx \sqrt{1 - \left(\frac{\varepsilon_F}{\Delta_t}\right)^2} \frac{\hbar\omega}{\pi\Delta_t}, \quad (21)$$

$$I_z(\omega) \approx \frac{1}{\sqrt{1 - \left(\frac{\varepsilon_F}{\Delta_t}\right)^2}} \frac{\hbar\omega}{\pi\Delta_t}. \quad (22)$$

Thus the result obtained here to the leading order in ω is consistent with that in the main text obtained by averaging optical conductivity of graphene sheets. Note that for $\varepsilon_F = 0$, $\phi_0 = \frac{\pi}{2}$ and thus $I_x(\omega)$ is written as

$$\begin{aligned} I_x(\omega) &\approx \frac{1}{\pi^2} \int_0^{2\pi} d\theta \left(1 + \frac{\hbar\omega}{2\varepsilon_0} \cos\theta\right) \sin^2\theta \int_{\Delta_-(\theta, \omega)}^{\Delta_+(\theta, \omega)} d\phi \phi^2 \\ &\approx \frac{1}{12\pi^3} \left(\frac{\hbar\omega}{\Delta_t}\right)^3, \end{aligned} \quad (23)$$

which is consistent with Eq. (8) in the main text.

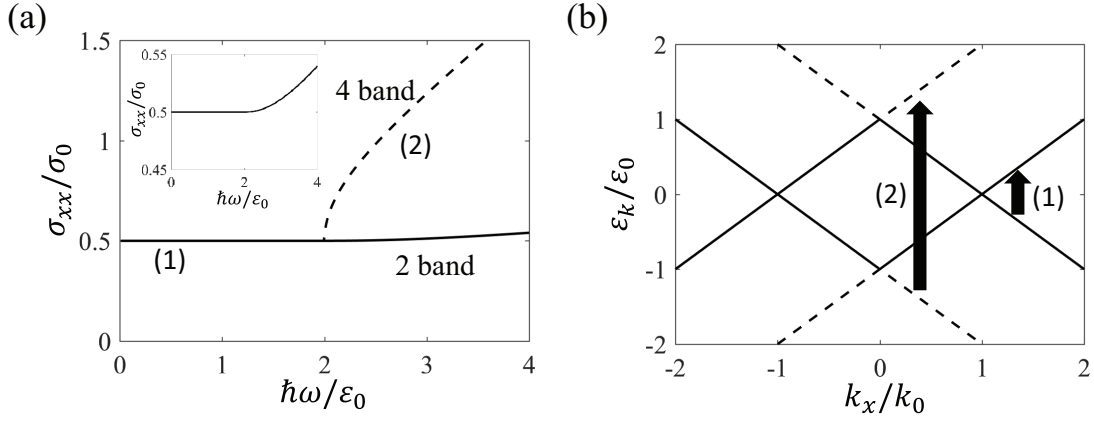


FIG. S2. (a) Optical conductivities for the 2-band (solid) and 4-band (dashed) models in the absence of tilt with zero Fermi energy. (b) Energy dispersions along the k_x axis for the 2-band (solid) and the 4-band (dashed) models. The thick arrows labeled by (1) and (2) represent interband transitions at low frequencies and high frequencies, respectively. The inset to (a) shows an enlarged view in σ_{xx} near $\hbar\omega = 2\varepsilon_0$ for the 2-band model.

Consider the following 4-band model [2, 3]:

$$H = \hbar v(k_x\sigma_x + k_y\sigma_y) + \hbar v k_z\tau_z\sigma_z + \varepsilon_0\tau_x + \hbar \mathbf{v}_t \cdot \mathbf{k}\sigma_0. \quad (25)$$

The eigenenergies are given by

$$\varepsilon_{\pm}^2 = \hbar^2 v^2 [(k_\rho \pm k_0)^2 + k_z^2] + \hbar \mathbf{v}_t \cdot \mathbf{k}, \quad (26)$$

where $\varepsilon_0 = \hbar v k_0$. Thus, ε_- has zero energy solutions forming a nodal line with the radius of k_0 . Note that the energy dispersion for the low-energy bands exactly match with that of the 2-band model [see Fig. S2 (b)].

Next, consider optical conductivities for the 2-band and 4-band models in the absence of tilt with zero Fermi energy, for simplicity [see Fig. S2 (a)]. At frequencies $\hbar\omega < 2\varepsilon_0$, the results for both models are in good agreement because the two models have the same low-energy electronic structure. This is true when NLSMs are tilted; a tilt term changes the shape of the band dispersion but not the wave functions, and thus there is no mixing between low and high energy states. At $\hbar\omega > 2\varepsilon_0$, however, the 4-band result strongly deviates from the 2-band result, showing a sharp increase at $\hbar\omega = 2\varepsilon_0$ due to interband transitions between high energy bands that are not captured by the 2-band model [4]. Thus in the frequency range where interband transitions involving high energy bands are negligible, the optical conductivity of NLSMs shows the exactly same qualitative features as described in the main text, despite the existence of the high energy bands that are not captured by the 2-band model.

VI. OPTICAL CONDUCTIVITY WITH OUT-OF-PLANE TILT

In this section, we consider the effect of the out-of-plane tilt, which is neglected for simplicity in the main text. Here we set the tilt velocity to be $\mathbf{v}_t = v_{t,x}\hat{x} + v_{t,z}\hat{z}$. The corresponding Hamiltonian describing the tilt can be written as $H_t = (\Delta_{t,x}\tilde{k}_x + \Delta_{t,z}\tilde{k}_z)\sigma_0$, where $\Delta_{t,i} = \hbar v_{t,i}k_0$ and $\tilde{k}_i = k_i/k_0$. Figures S3 (a) and (b) show the optical conductivity σ_{xx} with a fixed in-plane tilt energy $\Delta_{t,x} = 0.3\varepsilon_0$ and various out-of-plane tilt energies $\Delta_{t,z}/\varepsilon_0 = 0.0, 0.1, 0.5$. It is important to notice that at low frequencies the characteristic frequency dependence is robust against the change of $\Delta_{t,z}$; σ_{xx} for $\varepsilon_F = 0$ exhibits cubic frequency dependence while for $\varepsilon_F = 0.1\varepsilon_0$, σ_{xx} shows linear behavior, which is consistent with our results in the main text where we assume $\Delta_{t,z} = 0$. As we increase the frequency, the optical conductivity with $\Delta_{t,z} \neq 0$ begins to deviate from that with $\Delta_{t,z} = 0$ because the distortion of the FS by the out-of-plane tilt leads to a different geometry of the PS allowed for interband transitions. At high frequencies, however, the PS allowed for interband transitions fully covers the FS, leading to the same optical conductivity behavior regardless of the existence of tilt. Note that compared with the FS in the absence of the out-of-plane tilt (see Figs. 3 and 4 in the main text), the out-of-plane tilt simply distorts the electron and hole pockets making the FS asymmetric along the k_z -axis, but without changing any qualitative features such as the point contact between the electron and hole pockets, as shown in Figs. S3(c) and (d).

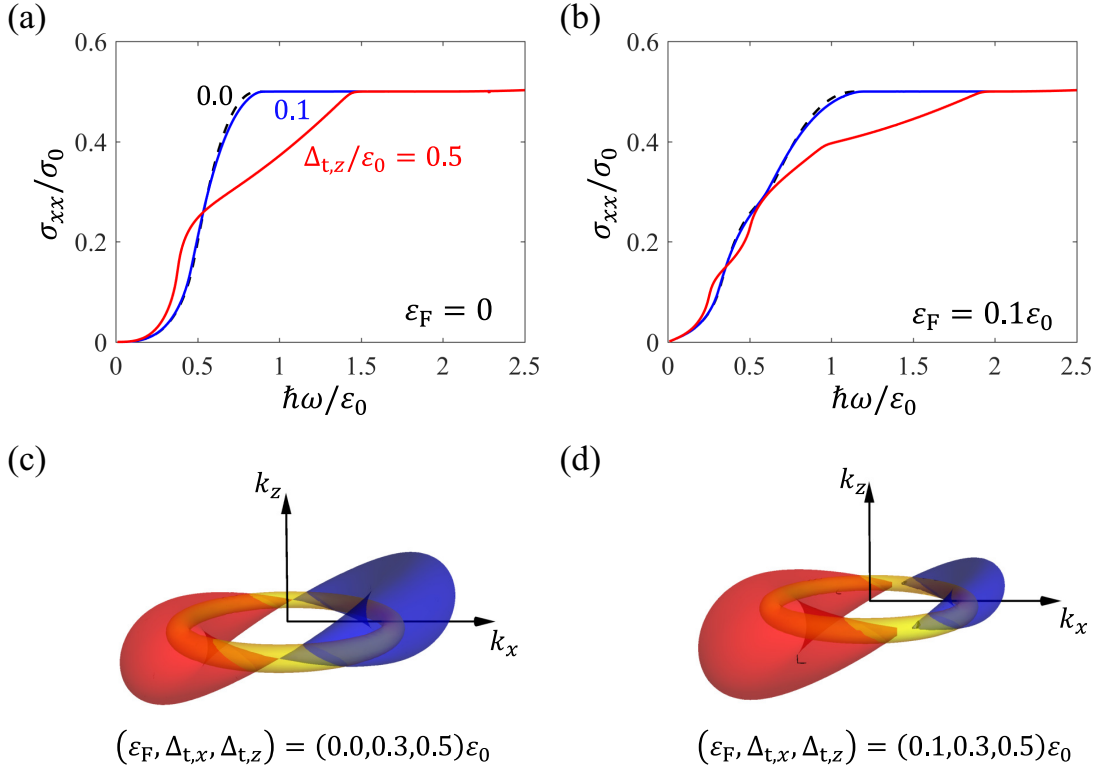


FIG. S3. (a), (b) Optical conductivities with (a) $\varepsilon_F = 0$ and (b) $\varepsilon_F = 0.1\varepsilon_0$ in the presence of both the in-plane ($\Delta_{t,x}$) and out-of-plane ($\Delta_{t,z}$) tilts. (c), (d) Electron and hole pockets exhibiting distorted Dupin cyclide due to the out-of-plane tilt. Note that the out-of-plane tilt just makes the FS asymmetric along the k_z -axis, without changing any essential features such as the point contact between the electron and hole pockets, thus leading to the same qualitative low and high frequency features in the optical conductivity compared with that obtained without the out-of-plane tilt.

VII. OPTICAL CONDUCTIVITY WITH FLUCTUATING IN-PLANE TILT

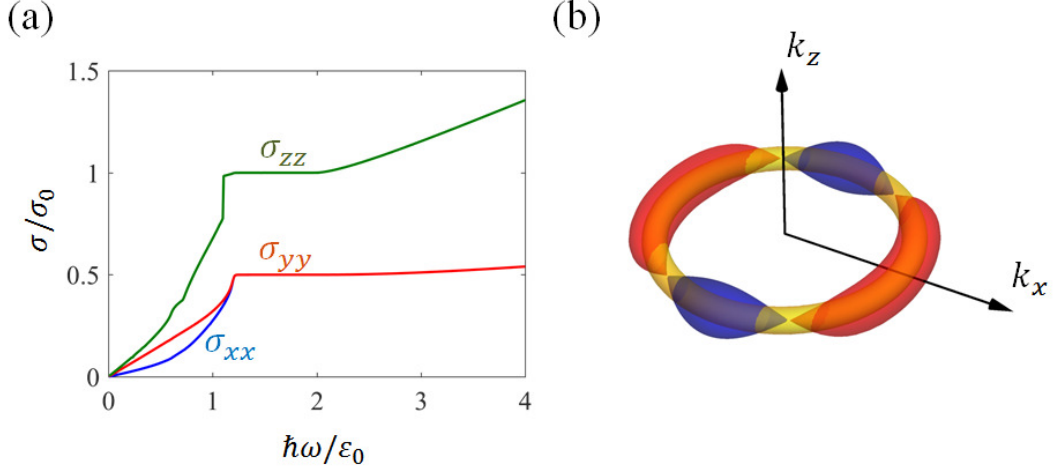


FIG. S4. (a) The optical conductivity in the presence of a fluctuating tilt and (b) the corresponding electron and hole pockets which meet at multiple points. Here we used a tilt term $H_t = \Delta_t \cos\left(\frac{3k_x}{k_0}\right)\sigma_0$ and $\Delta_t = 0.6\varepsilon_0$.

Here we consider the case where the tilt term fluctuates along the nodal line so that the electron and hole pockets

meet at multiple points, as shown in Fig. S4 (b). In such cases, the FS does not exhibit the Dupin cyclide geometry described in the main text, yet the underlying physics is essentially the same as the case where only a linear tilt exists. Note that at low frequencies, the PS allowed for interband transitions have the same geometry as the case where only a linear tilt exists, except for the number of the contact points [see Fig. S4 (b)]. Thus the optical conductivity shows the same linear behavior at low frequencies, as shown in Fig. S4 (a).

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